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Enhanced Thermoelectric Properties of Misfit $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$: Isovalent Substitutions and Selective Phonon Scattering

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Abstract: Layered Bi-misfit cobaltates, such as $\text{Bi}_2\text{Sr}_2\text{Co}_2\text{O}_y$, are the natural superlattice of an electrically insulating rocksalt (RS) type $\text{Bi}_2\text{Sr}_2\text{O}_4$ layer and electrically conducting CoO_2 layer, stacked along the crystallographic c-axis. RS and CoO_2 layers are related through charge compensation reactions (or charge transfer). Therefore, thermoelectric transport properties are affected when doping or substitution is carried out in the RS layer. In this work, we have shown improved thermoelectric properties of spark plasma sintered $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$ alloys ($x = 0, 0.3$ and 0.5). The substitution of Ca atoms affects the thermal properties by introducing point-defect phonon scattering, while the electronic conductivity and thermopower remain unaltered.

Keywords: misfit cobaltates; thermoelectric properties; misfit-layer; isovalent substitutions



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1. Introduction

The search for renewable energy sources and energy recovery methods is an active area of research. Direct conversion of waste heat into electricity using the thermoelectric Seebeck effect has received attention in recent years [1]. High efficiency in a thermoelectric module requires a high “figure of merit” (zT), which is a balance between power factor and thermal conductivity ($zT = (\sigma S^2)T/k$, where σ , S , k , and T are the electronic conductivity, Seebeck coefficient, thermal conductivity, and mean operational temperature, respectively). For high TE efficiency, a high zT is mandatory, i.e., a large power factor ($PF = \sigma S^2$) and low k are essential elements [2]. Recent studies in layered materials based on bismuth telluride, silicene films, tin selenide, and multilayer structures of dissimilar 2D materials have demonstrated zT values above 2 at room temperature [3–6]. However, oxide materials will be an alternative solution for high-temperature thermoelectric application because of their chemical stability at high temperatures, non-toxicity, and less expensive constituent elements [7–11].

Soon after the discovery of a large Seebeck coefficient ($\sim 100 \mu\text{V}/\text{K}$) and relatively high electrical conductivity ($\sim 5000 \text{ S}/\text{cm}$) in $\text{Na}_{0.5}\text{CoO}_2$ (NCO) at room temperature, the layered cobaltates are considered as a promising class of compounds for thermoelectric energy conversion [12]. Aside from cobaltates, BiCuSeO oxyselenides have also been identified as potential thermoelectric materials, showing a zT close to 1 [13] and Seebeck coefficient around $500 \mu\text{V}/\text{K}$ [14]. The misfit cobaltate [15] $\text{Bi}_2\text{Sr}_2\text{Co}_2\text{O}_y$ (BSCO) is a p -type thermoelectric material and has shown a figure of merit (zT) > 1 at 1000 K [16].

NCO and BSCO share a common CdI_2 -type CoO_2 layer in their crystal structures [17]. The CoO_2 layers in BSCO are separated by the rocksalt (RS)-type $\text{Bi}_2\text{Sr}_2\text{O}_{4-\delta}$ layers. RS and CoO_2 layers do not fit along the crystallographic b-axis (because the b parameter of RS

> b-parameter of CoO₂), hence the name misfit [18]. The incommensurate nature of the crystal structure results in the ultralow cross plane [19,20] and low in-plane [21] thermal conductivity, which is one of the key factors responsible for the high zT.

It is well known that the CoO₂ layer governs the electronic transport properties of misfit cobaltates because the RS layer is electrically insulating in nature [17]. Nevertheless, these two layers are intimately related to each other through charge transfer [22]. Given that NCO and BSCO share common triangular CoO₂ layers, their electronic structure near Fermi energy (E_F) are quite similar [23]. At room temperature, σ of BSCO is lower (~330 S/cm) than in NCO, but S remains high for both compounds (100–120 μ V/K) [24]. At high Na doping in NCO, σ and S remained very high [25], whereas Pb doping in BSCO also showed improved σ , and hence improved PF [26,27]. However, σ decreased drastically in Bi₂M₂Co₂O_y (M = Ba, Sr and Ca) when Ba was substituted by Sr or Ca [28]. Note that even though the RS layer is electrically insulating, doping or substitution in the RS layer produced significant change in the transport properties. In fact, the electronic band structure near the Fermi energy (E_F) was significantly affected (transfer of spectral weight from the broad itinerant band to an incoherent regime was observed) in Bi₂M₂Co₂O_y (M = Ba, Sr, and Ca) when Ba was replaced by Sr or Ca [23]. Therefore, RS layers provide tunable possibilities to understand the charge transfer mechanism and optimize conditions to achieve the best thermoelectric performance.

To this aim, several strategies were employed in the single crystal and polycrystals of BSCO. For example, an improved zT (0.023 at 300 K) was reported in Pb-substituted BSCO single crystals [26]. A different set of single crystals of composition Bi_{2.3-x}Pb_xSr_{2.6}Co₂O_y (0 ≤ x ≤ 0.44) showed enhanced S and σ upon Pb substitution in the RS layer (PF ~ 9 μ W/cm.K² at 100 K) [27]. Polycrystalline Bi₂Sr₂Co₂O_y showed high-temperature stability and zT ~ 0.2 at 1000 K, however this was very much dependent on the composition [29]. Ca-substituted polycrystalline sintered BSCO prepared by the sol-gel method showed lower zT ~ 0.007 at 300 K [30,31]. Modifying the sintering conditions, zT = 0.05 in BSCO was achieved at 150 K [32]. To the best of our knowledge, high-temperature thermoelectric properties of Bi₂Sr_{2-x}Ca_xCo₂O_y (x = 0, 0.3 and 0.5) samples have not been reported yet.

In this work, we investigate the temperature dependence (340 < T < 750 K) of the thermoelectric properties of spark plasma sintered (SPS) parent Bi₂Sr₂Co₂O_y and their Bi₂Sr_{2-x}Ca_xCo₂O_y alloys (x = 0.3 and 0.5). Although isovalent ion substitutions (Sr⁺² by Ca⁺²) did not significantly impact the electronic properties, a strong decrease in κ was found. This result reflects the selective phonon scattering that occurred by point defects in the misfit cobaltates, which caused an improved zT ~ 0.02 at 300 K and 0.09 at 740 K in Bi₂Sr_{2-x}Ca_xCo₂O_y alloys (within x = 0.3 and 0.5).

2. Experimental Methods

Synthesis: Bi₂Sr_{2-x}Ca_xCo₂O_y (x = 0, 0.3 and 0.5) polycrystalline pellets were synthesized by conventional high temperature solid-state reactions [29]. A stoichiometric mixture of Co₃O₄, Bi₂O₃, SrCO₃, and CaCO₃ were mixed in an agate mortar to obtain a homogeneous powder. The powder was pressed using a stainless-steel die into a pellet under uniaxial pressure. The pellet was slowly heated up to 1070 K and calcined for 40 h at the same temperature in air and then slowly cooled down to room temperature. The calcined pellet was ground into a fine powder and then pressed again into a pellet in uniaxial pressure for 30 min to achieve dense pellets. Then, the pellets were placed into a tubular furnace and sintered at 1160 K for 20 h at 100 sccm pure oxygen flow. Samples were prepared by the SPS method at 920 K in a uniaxial pressure of 3.1 kN (~40 MPa) to achieve high density (~94.3%) for thermoelectric transport measurement.

Characterization: Polycrystalline sample quality and θ -2 θ diffraction patterns were checked by X-ray diffraction technique at room temperature using a Malvern-Panalytical X'pert Pro MRD (multipurpose X-ray diffractometer, Malvern, UK) tuned at Cu K-alpha radiation of wavelength 1.54598 Å. Out-of-plane lattice parameters were calculated from

(005) reflections. X-ray photoelectron spectroscopy (XPS) measurements were carried out at room temperature in order to identify the elements and their oxidation states.

The Raman spectra were recorded by a T64000 Raman spectrometer manufactured by HORIBA Jobin Yvon (Chilly-Mazarin, France) in single grating mode with 2400 lines and a spectral resolution better than 0.4 cm^{-1} . The measurements were performed by focusing a diode laser (532 nm) onto the sample with a $100\times$ microscope objective. The power of the laser was kept as low as possible ($\sim 0.5 \text{ mW}$) to avoid any possible damage from self-heating of the samples.

Transport properties: The Seebeck effect and electronic conductivity measurements were carried out simultaneously from 350 to 750 K in a LINSEIS instrument (in a 1 atm helium pressure). Thermal diffusivity measurements were carried out in a NETZSCH LFA instrument (with continuous N_2 gas flow). Pellets were cut into $2 \times 2.5 \times 8 \text{ mm}^3$ and $6 \times 6 \times 2 \text{ mm}^3$ dimensions for the Seebeck effect and thermal diffusivity measurements, respectively. Thermal conductivity was calculated from the relation, $\kappa_{total} = DC_p d$, where D , C_p , and d are thermal diffusivities, specific heat capacity, and density of the pellet, respectively. It is important to note that due to the polycrystalline nature of the samples, there are no preferred orientations in the crystal structure. Thus, we did not find anisotropies in the thermal and electronic properties of synthesized samples. The measurement of thermal conductivity is subject to an uncertainty of approximately 5%, which is dependent on the chosen characterization method and the underlying assumptions made in the modeling of thermal properties. The three-omega technique is widely regarded as a highly effective method for determining thermal conductivity, and it has been shown to achieve uncertainties below 1% when specific experimental conditions are met [33]. In comparison, the flash method is associated with a relatively low uncertainty of around 3 to 5% for the estimation of thermal diffusivity [34].

3. Results and Discussion

3.1. Structural and Elementary Characterization

Figure 1 depicts the powder X-ray diffraction (XRD) patterns of the $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$ ($x = 0, 0.3$ and 0.5) samples. The powder XRD patterns are similar to the polycrystalline samples synthesized by others [26]. No impurity phases were detected within the detection limit of the diffractometer. A systematic shift of (005) reflection in 2θ position can be observed with increasing Ca content, which indicates that the out-of-plane cell parameters decrease with increasing Ca content. As the ionic radii of Ca^{+2} ion is smaller than Sr^{+2} ions, the unit cell undergoes a systematic contraction [35]. The change in the c -parameter upon substitution confirms the incorporation of Ca atom in the BSCO unit cell.

To prove the incorporation of calcium in the BSCO lattice, Raman spectra measurements were also carried out at room temperature. Figure 2 represents the recorded Raman spectra of $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$ ($x = 0, 0.3$ and 0.5) samples from 500 to 950 cm^{-1} at 300 K . Two prominent phonon peaks can be observed for all samples at $\sim 618 \text{ cm}^{-1}$ and $\sim 815 \text{ cm}^{-1}$. The peaks at 618 cm^{-1} can be assigned to A_{1g} modes, comparing with the Raman spectra of single crystals of similar composition [19]. The A_{1g} modes represent the out-of-plane vibrational mode of oxygen atom. A slight right shift in the position of Raman peak in Figure 2b can be observed with increasing Ca content. This can be explained by the increase in bond strength of the Ca-O bond, with respect to the Sr-O bond.

Element detection and oxidation states of cobalt ions were obtained from XPS, as shown in Figure 3. The overall spectrum contains prominent peaks of Bi, Sr, Ca, Co, and O (see Figure 3a). The high-resolution core level XPS spectrum of Ca-2p is depicted in Figure 3b. As can be seen in Figure 3b, the parent composition did not contain Ca, while the alloys showed prominent peaks of Ca-2p. The high-resolution core level spectrum of Co-2p of $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$ ($x = 0, 0.3$ and 0.5) compositions is depicted in Figure 3c. The Co-2p spectrum was split into two components—Co $2p^{3/2}$ and Co $2p^{1/2}$ —due to strong spin-orbit coupling at an intensity ratio of $\sim 2:1$. The appearance of the satellite peaks from both parts of the 2p components at higher binding energies to the main peaks indicates the

presence of mixed valence cobalt ions. Misfit cobaltates showed satellite peaks due to the presence of $\text{Co}^{+3}/\text{Co}^{+4}$ pair. The line shape of the Co-2p core-level spectrum indicates the presence of low-spin (LS) Co^{+3} ions. Valence band spectrums of the parent and alloys are depicted in Figure 3d. They are very similar to those obtained in single crystals [36]. The density of states (DOS) near the Fermi energy (E_F) is dominated by the hybrid molecular orbitals of Co-3d and O-2p. The sharp peak around 1.5 eV is due to the presence of LS Co^{+3} ions ($t_{2g}^6 e_g^0$). A small amount of DOS is embedded in the E_F ; therefore, the compounds were expected to show metallic behavior in their transport properties.

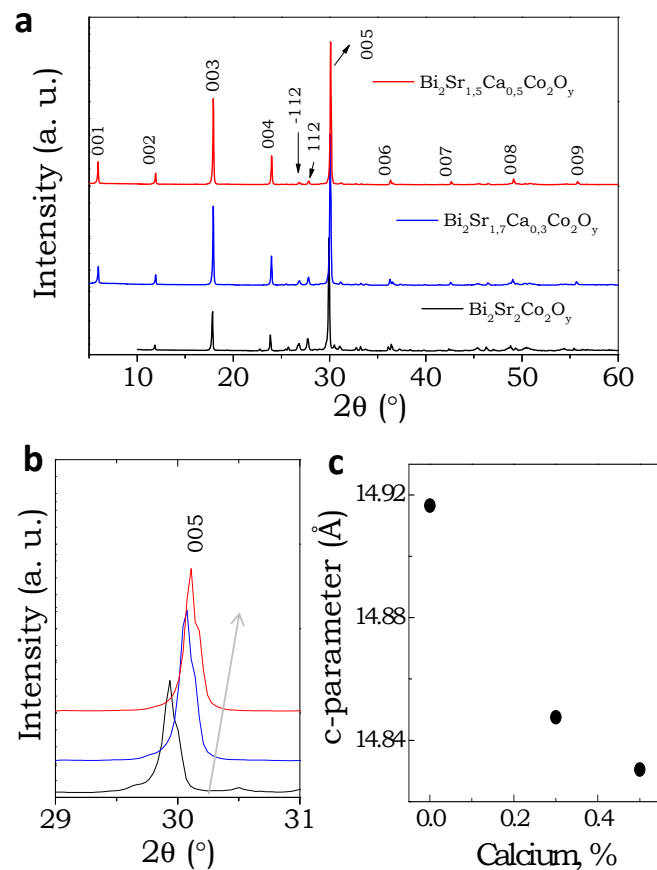


Figure 1. X-ray diffraction (XRD) patterns. (a) Powder X-ray diffraction patterns of $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$ ($x = 0, 0.3$ and 0.5) samples, (b) shift of the 005 reflections in 2θ upon substitution, and (c) change of the c-parameter with increasing calcium content.

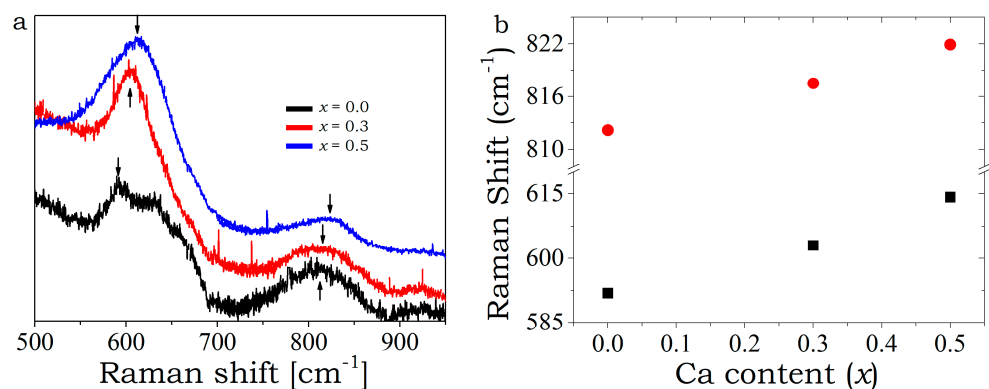


Figure 2. (a) Raman spectra of $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$ ($x = 0, 0.3$ and 0.5) samples at 300 K cm^{-1} . (b) Peak positions of Raman band marked with arrows.

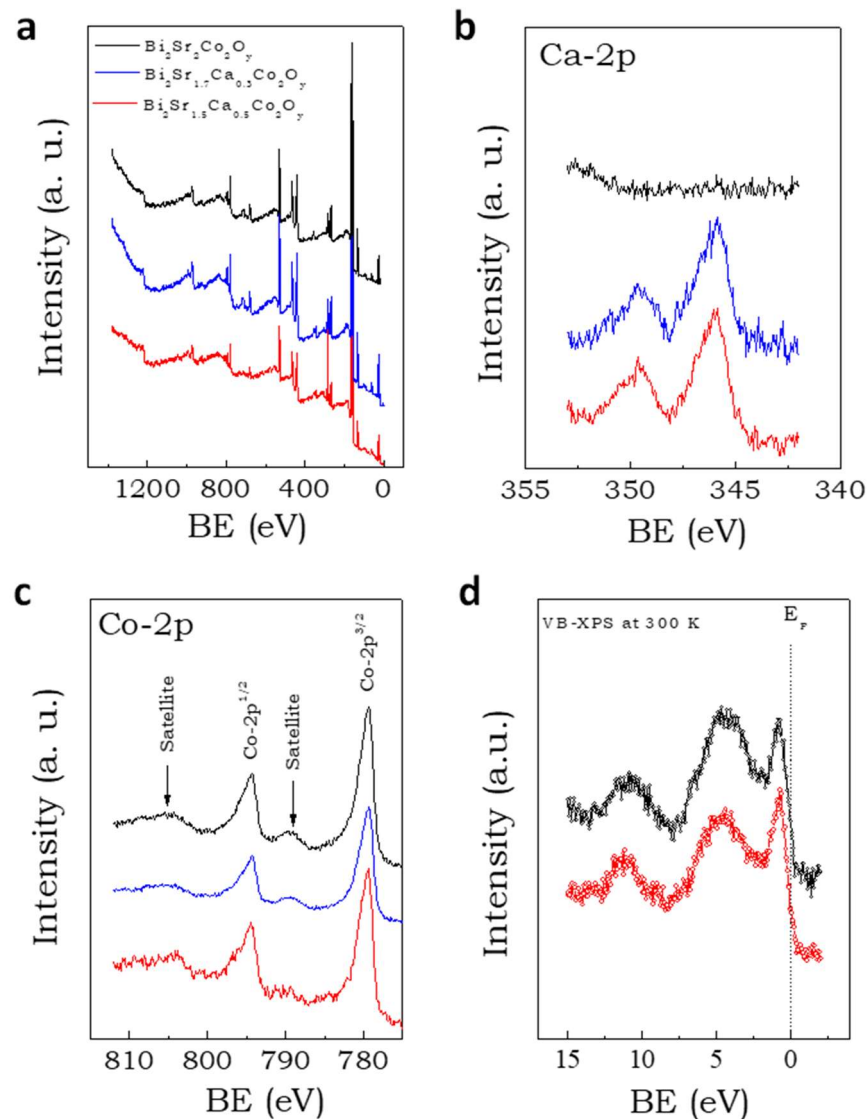


Figure 3. X-ray photoelectron spectroscopy. (a) Overview of the XPS spectra of $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$ for $x = 0$ (black line), 0.3 (blue) and 0.5 (red). (b) High-resolution core level XPS spectra of Ca-2p for $x = 0$ (black line), 0.3 (blue) and 0.5 (red), (c) high-resolution core level XPS of Co-2p for $x = 0$ (black line), 0.3 (blue) and 0.5 (red). (d) valence band-XPS spectra of $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$ for $x = 0.3$ (black) and 0.5 (red) samples.

3.2. Thermoelectric Transport Properties

Temperature dependence of S and σ of $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$ ($x = 0, 0.3$ and 0.5) samples are depicted in Figure 4. σ is ~ 90 S/cm at 340 K for the parent composition (see in Figure 4a). We found that σ decreases linearly with increasing temperature from 340–750 K, which is typically observed in metallic conductors. This result is consistent with the previous valence band XPS measurements, where a small amount of DOS was found near E_F (see Figure 3d). The positive value of S for the parent composition and their alloys indicates the p -type nature of the compounds (Figure 4b). This also points out the presence of $\text{Co}^{+3}/\text{Co}^{+4}$ mixed valence states in the CoO_2 layer. The S reached a value of $+108$ $\mu\text{V}/\text{K}$ for the parent composition and increased linearly with increasing temperature up to 145 $\mu\text{V}/\text{K}$ at 750 K. This is a typical metallic-like behavior.

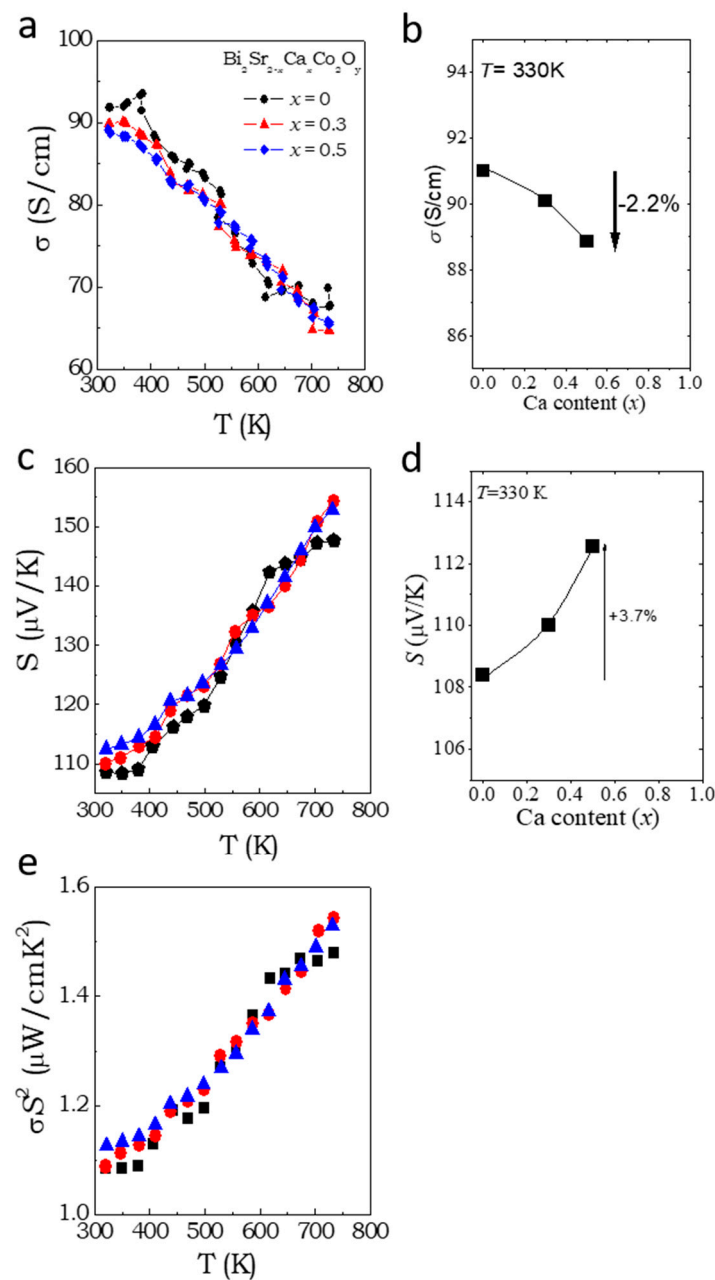


Figure 4. Electronic conductivity and thermoelectric Seebeck effect. Temperature dependent (a) electronic conductivity, (c) thermoelectric power, and (e) power factor of Bi₂Sr_{2-x}Ca_xCo₂O_y (x = 0, 0.3 and 0.5) samples. Effect of calcium substitution on (b) electronic conductivity and (d) Seebeck coefficient at 330 K.

The influence of calcium substitution on the electronic conductivity and Seebeck coefficient of the BSCO lattice is displayed in Figure 4b,d. The conductivity decreases by a small margin (2.2% drop within the range of x = 0–0.5 of Ca substitution) while the Seebeck coefficient increases slightly (3.7% increase within x = 0–0.5). These changes are driven by variations in the concentration of *p*-type charge carriers caused by Ca²⁺ substitution for Sr²⁺ ions, which is isovalent and should not affect carrier concentration. However, the valence of cobalt ions in the CoO₂ layer, which controls the carrier concentration, is linked to the misfit ratio in BSCO single crystals, as revealed in the literature [37]. Typically, in standard semiconductors or semimetals, the electronic conductivity and Seebeck coefficient exhibit opposing behavior with doping or substitution, as observed in our samples. However, in

the literature [37], it was shown that the valence of cobalt ions in the CoO₂ layer is related to the misfit ratio in the single crystals of BSCO, as follows;

$$v_{\text{Co}} = 4 - \frac{\alpha}{q}; q = \frac{b_{\text{RS}}}{b_{\text{CoO}_2}} \quad (1)$$

where, v_{Co} , α , and q are the valence of cobalt ion, charge of electrically insulating RS layer, and the misfit ratio of b_{RS} to b_{CoO_2} (b_{RS} and b_{CoO_2} are the b-lattice parameters of the rock salt type and CoO₂ layer), respectively. We found that the value of “ α ” remained constant despite isovalent substitutions. Hence, the alteration in “ v ” “Co” is expected to be minimal due to the substitution of Ca for Ca⁺² in Bi₂Sr_{2-x}Ca_xCo₂O_y, within the range of $x = 0.3$ to 0.5 . This may result from either decreased p -type carrier concentration in the CoO₂ layer due to oxygen vacancy formation or minimal change in the misfit ratio. To uncover the dominant factor affecting the lattice parameters, we performed a calculation of the average in-plane lattice parameters of Bi₂Sr_{2-x}Ca_xCo₂O_y ($x = 0, 0.3$, and 0.5) using X-ray diffraction (XRD) patterns. The results revealed a decrease in the in-plane parameters from 5.036 to 5.026 Å (a contraction of 0.19%) for $x = 0-0.5$, while the out-of-plane parameters showed a more significant drop from 14.918 to 14.812 Å (a reduction of 0.71%). This indicates that the substitution of Sr²⁺ ions by Ca²⁺ ions has a dominant effect on the out-of-plane direction, while the in-plane parameters remain largely unaffected.

Since the rock-salt layer is the primary contributor to the unit cell and XRD pattern, we consider the average in-plane parameters as the average b-parameter of the rock-salt layer. This leads us to the conclusion that the substitution of Sr²⁺ ions by Ca²⁺ ions does not significantly impact the misfit ratio or the valence of cobalt, as reflected in their transport and thermoelectric properties.

It is also unlikely that the misfit ratio changes due to oxygen vacancies, as all of our samples were sintered under the same conditions and with high oxygen flow.

The electrical conductivity of the undoped sample exhibits slight fluctuations around 400 K, as depicted in Figure 4a. These variations could be a result of slight fluctuations in the experimental setup. Nevertheless, similar variations are also observed in the k measurements (Figure 5a), indicating a potential correlation between the two. However, we do not know the exact underlying mechanism behind these fluctuations.

Moreover, the S in the single crystal [38] and polycrystals [30] of BSCO below 300 K shows an interesting behavior. It increases in the temperature range between 3–150 K and then remains constant above 200 K. The temperature-independent S is an indication of the contribution of narrowband (i.e., incoherent charge carriers) to the thermopower [39]. Due to the triangular distortion in the CoO₂ layer, t_{2g} orbital splits into in-plane Co e'_g and out-of-plane Co a_{1g} orbitals [23]. The states near E_F have a_{1g} symmetry, and electrons undergo hopping transport in the neighbouring Co a_{1g} states [40]. Therefore, for localized interacting charge carriers (at the high-temperature limit, i.e., when bandwidth, $W \ll$ thermal energy, $k_B T$), S is governed by the statistical distribution of charge carriers over available sites, given by Heike’s formula [39] as follows;

$$S = - \frac{k_B}{e} \ln \left(\frac{c}{1-c} \right), \quad (2)$$

where, k_B , e , and c are the Boltzmann constant, electron charge, and the ratio of particles (holes in this case) to sites, respectively.

Although the polycrystalline samples in this work did not show any sign of saturation of S above 340 K, a rough estimation of $c = 0.22$ was obtained from the measured average $S = +110 \mu\text{V}/\text{K}$ by using Equation (2). Here, c is directly related to the oxidation state of cobalt. From the framework of Heike’s formula, c can be simplified to the number of charge carriers per unit cell. Therefore, roughly, an oxidation state of +3.22 can be estimated for cobalt, which is slightly less than the reported valence of cobalt in BSCO (of composition Bi_{2.1}Sr_{2.15}Co₂O_{8+ δ}) [41]. Although the possibility of spin and orbital degrees of freedom (β)

was proposed to contribute to the S in misfit cobaltates [42,43], recent reports in the thin films of misfit cobaltates showed that the use of β factor overestimates the measured S at 300 K [44]. The temperature-dependence of the PF of BSCO and their alloys are depicted in Figure 4c. The σS^2 of all the samples are $\sim 1.1 \mu\text{W}/\text{cmK}^2$ at room temperature and increased to a maximum value $\sim 1.55 \mu\text{W}/\text{cmK}^2$ at 775 K.

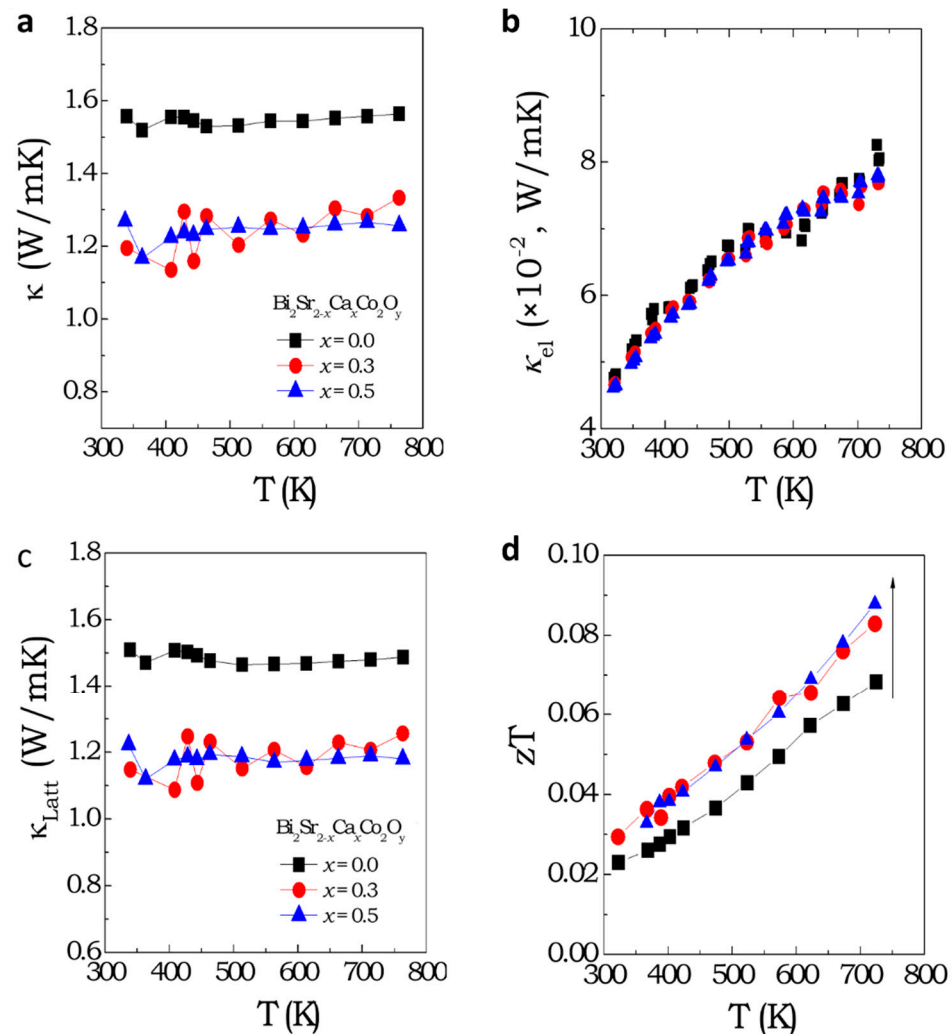


Figure 5. Thermal transport and thermoelectric figure of merit. (a) Thermal conductivity as a function of temperature, (b) calculated electronic part of the thermal conductivity from the electrical conductivity and Lorentz number by using the Wiedemann-Franz law, (c) subtracted lattice part of the thermal conductivity, and (d) temperature dependence of the thermoelectric figure of merit of $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$ (x = 0, 0.3 and 0.5) samples.

Figure 5a depicts κ as a function of the temperature of $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$ (x = 0, 0.3 and 0.5) compounds from 340–750 K. The κ of the parent BSCO polycrystalline pellet is $\sim 1.6 \text{ W/mK}$ at 340 K, which is lower than the thermal conductivity value reported in a single crystal [21]. Moreover, we observe that κ exhibits a very weak temperature-dependence. The low κ of the misfit cobaltates is mainly attributed to the phonon scattering at the CoO_2 and RS interfaces and the highly ordered RS layer [20]. However, the lower κ for polycrystalline samples reflects the important contribution of phonon scattering at the grain boundaries. In the literature, a large discrepancy in the absolute value of the thermal conductivity of BSCO polycrystals and single crystal is observed, which varies from ~ 0.8 to $\sim 4 \text{ W/mK}$ at 300 K. This variation is attributed to the different methods of sample preparation [19,27], measurement techniques [20,21,45], as well as the sintering

process followed before measurements [32]. A comparison of the reported κ at 300 K is presented in Table 1. The temperature-independent nature of κ suggests that the grain boundaries and impurities mainly dominate the phonon scattering in the samples. The measured κ of the parent $\text{Bi}_2\text{Sr}_2\text{Co}_2\text{O}_y$ at 340 K is comparable with previous reports in polycrystalline samples [29,32] prepared by similar high-temperature solid state reactions and sol-gel methods, respectively.

Table 1. Comparison of the measured thermal conductivity of $\text{Bi}_2\text{Sr}_2\text{Co}_2\text{O}_y$ polycrystalline samples with the reported values in the literature.

Composition	Crystallinity	Method of Synthesis	κ (W/mK)	T (K)	Sintering Method	Method of Measurement	Reference
$\text{Bi}_2\text{Sr}_2\text{Co}_2\text{O}_y$	Single crystal	Floating zone technique	1.8	300	-	4 probe method in PPMS	Diao, et al. [45]
$\text{Bi}_2\text{Sr}_2\text{Co}_2\text{O}_y$	Whisker	Sintered precursor (SP) method	2.2 (in-plane)	300	-	Diffusivity	Funahashi, et al. [16]
$\text{Bi}_2\text{Sr}_2\text{Co}_2\text{O}_y$	Single crystal	traveling-solvent floating-zone method	2.0 (b-axis) 2.4 (a-axis)	300	-	Herman method	Satake, et al. [21]
$\text{Bi}_2\text{Sr}_2\text{Co}_2\text{O}_y$	Single crystal	Flux method	0.24 (ab-plane)	300	-	Time domain thermoreflectance	Li, et al. [19]
$\text{Bi}_{2-x}\text{Pb}_x\text{Sr}_2\text{Co}_2\text{O}_y$	Single crystal	traveling-solvent-floating-zone technique	0.45 (along a-axis) 3.0 (along b & c-axes)	300	-	Steady state method	Terasaki, et al. [20]
$\text{Bi}_{2-x}\text{Pb}_x\text{Sr}_2\text{Co}_2\text{O}_y$	Single crystal	optical floating-zone method	4.4 (x = 0) 3.0 (x = 0.35) 2.8 (x = 0.55)	300	-	Closed cycle refrigerator (direct heat pulse)	Hsu, et al. [26]
$\text{Bi}_2\text{Sr}_2\text{Co}_2\text{O}_y$	Polycrystalline	Solid state heat treatment	0.8–1.4	400	Sintered at 1113 K in air	Laser flash	Funahashi, et al. [29]
$\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$	Polycrystalline	Sol-gel	3.5 (x = 0) 2.0 (x = 0.3) 2.8 (x = 0.5)	300	Sintered at 1073 K	4 probe method in PPMS	Yin, et al. [30,31]
$\text{Bi}_2\text{Sr}_2\text{Co}_2\text{O}_y$	Polycrystalline	Sol-gel	1.8 (0 Tesla) 1.6 (4 Tesla) 1.5 (8 Tesla)	300	high magnetic field sintering	4 probe method in PPMS	Huang, et al. [32]
$\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$	polycrystalline	Solid state reactions at high temperature	1.6 (x = 0) 1.2 (x = 0.3) 1.3 (x = 0.5)	340	Spark plasma sintered	Laser flash	This work

A drop in thermal conductivity (κ) from 1.6 to 1.2 W/mK was observed at 340 K due to the substitution of Sr atoms with Ca atoms, linked to changes in the crystal structure. Despite typical phonon–phonon scattering in thin film semiconductors at high temperatures [46,47], the polycrystalline nature of the samples limits phonon MFP at grain boundaries, resulting in temperature-independent κ . The addition of dopants with varying ionic radii also reduces thermal conductivity through impurity scattering. It is well known that the measured κ consist of two different parts; one is the electronic part (κ_{el}) and the other the lattice part (κ_{Latt}). The κ_{el} is directly proportional to the electronic conductivity (σ) according to the Wiedeman-Frentz law. The relation can be mathematically expressed as; $\kappa_{\text{el}} = L\sigma T$, where L is the Lorentz number. Therefore, κ_{Latt} can be separated from the measured κ if L is known. One possibility is to consider the standard value of L, which is $\sim 2.45 \times 10^{-8} \text{ W/S}^{-1}\text{K}^{-2}$, and another possibility is to estimate L from measured thermopower data. L is directly related to the scattering factor (ξ) and the reduced Fermi energy (η) by the following mathematical relation [48];

$$L = \left(\frac{k_B}{e}\right)^2 \left(\frac{(\xi + 7/2)F_{\xi + \frac{5}{2}}(\eta)}{(\xi + 3/2)F_{\xi + \frac{1}{2}}(\eta)} - \left(\frac{(\xi + \frac{5}{2})F_{\xi + \frac{3}{2}}(\eta)}{(\xi + \frac{3}{2})F_{\xi + \frac{1}{2}}(\eta)} \right)^2 \right), \quad (3)$$

However, η is needed to calculate L from Equation (2). η can be obtained from the measured Seebeck data from Figure 3b by using the single parabolic band model given by;

$$S = \pm \frac{k_B}{e} \left(\frac{(\xi + 5/2)F_{\xi+3/2}(\eta)}{(\xi + 3/2)F_{\xi+1/2}(\eta)} - \eta \right), \quad (4)$$

where, $F_n(\eta)$ is n th order Fermi integral: $F_n(\eta) = \int_0^\infty \frac{x^n}{1+e^{x-\eta}} dx$ and $\eta = \frac{E_F}{k_B T}$, where E_F is the Fermi energy and k_B is the Boltzmann constant. Here, we assume that acoustic phonon is the main scattering mechanism of electrons, i.e., $\xi = -\frac{1}{2}$. Although the Seebeck coefficient was expressed by the single parabolic model (in Equation (4)), the actual electronic band structure of the misfit cobaltates is rather complex (as has been described before). All the above calculations with simple assumptions were carried out only in order to obtain L . The calculated L from the measured S is within the range of $\sim 1.61 \times 10^{-8} \text{ WS}^{-1}\text{K}^{-2}$. The separated k_{el} is shown in Figure 5b, which is two orders of magnitude lower than the κ_{Latt} part (see Figure 5c). Therefore, the reduced κ at 340 K is mainly due to phonons scattering at the point defects in the RS layer originated from the substitution of Sr ions by Ca. Figure 5d represents the zT value of parent $\text{Bi}_2\text{Sr}_2\text{Co}_2\text{O}_y$ and $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$ ($x = 0.3, 0.5$) compounds. The highest zT value of 0.09 at 750 K was achieved for the $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$ ($x = 0.3$ and 0.5) samples. A fair comparison of the estimated zT values of our samples with the reported values in the literature is difficult due to that fact that measured thermal conductivity values varies significantly, as described in Table 1.

4. Summary

In summary, polycrystalline bulk samples of $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$ ($x = 0, 0.3$ and 0.5) were synthesized by conventional solid-state reactions. The substitution of Sr^{2+} ions by Ca^{2+} ions was confirmed through X-ray diffraction, X-ray photoelectron spectroscopy, and Raman spectroscopy. The isovalent substitutions of Sr^{2+} ions in the BSCO lattice results in a negligible impact on electronic and thermoelectric transport properties, but a significant effect on lattice thermal conductivity due to selective phonon scattering.

This reduction leads to a marked improvement in the overall thermoelectric figure-of-merit. Our findings highlight that selective phonon scattering can play a crucial role in enhancing the thermoelectric performance of misfit layer compounds, such as $\text{Bi}_2\text{Sr}_{2-x}\text{Ca}_x\text{Co}_2\text{O}_y$.

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